

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

2SB1204 — PNP Epitaxial Planar Silicon Transistor

High-Current Switching Applications

Applications

· Relay drivers, high-speed inverters, converters, and other general high-current switching applications

Features

- Low collector-to-emitter saturation voltage
- · High current and high fT
- · Excellent linearity of hFE

- Fast switching speed
- Small and slim package making it easy to make 2SB1204-applied sets smaller

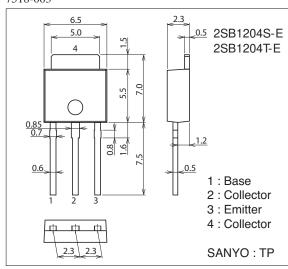
Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		-60	V
Collector-to-Emitter Voltage	VCEO		-50	V
Emitter-to-Base Voltage	VEBO		-6	V
Collector Current	IC		-8	Α
Collector Current (Pulse)	ICP		-12	Α
0 11	De		1	W
Collector Dissipation	PC	Tc=25°C	20	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

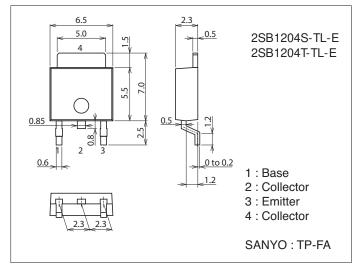
Package Dimensions unit: mm (typ)

7518-003



Package Dimensions unit : mm (typ)

7003-003



Product & Package Information

- Package : TP
- JEITA, JEDEC: SC-64, TO-251
- Minimum Packing Quantity: 500 pcs./bag

Marking (TP, TP-FA)



- Package : TP-FA
- JEITA, JEDEC: SC-63, TO-252
- Minimum Packing Quantity: 700 pcs./reel

Packing Type (TP-FA): TL





SANYO Semiconductor Co., Ltd.

http://semicon.sanyo.com/en/network

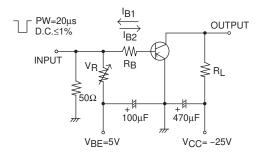
Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
Farameter	Symbol		min	typ	max	Oill	
Collector Cutoff Current	ICBO	V _{CB} = -40V, I _E =0A			-1	μΑ	
Emitter Cutoff Current	IEBO	V _{EB} = -4V, I _C =0A			-1	μΑ	
DC Current Gain	hFE1	V _{CE} = -2V, I _C = -0.5A	70*		400*		
Do Current Gain	hFE2	V _{CE} = -2V, I _C = -6A	35				
Gain-Bandwidth Product	fT	V _{CE} = -5V, I _C = -1A		130		MHz	
Output Capacitance	Cob	V _{CB} = -10V, f=1MHz		95		pF	
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)	I _C = -4A, I _B = -0.2A		-250	-500	mV	
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C = -4A, I _B = -0.2A		-0.95	-1.3	V	
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC= -10μA, IE=0A	-60			V	
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC= -1mA, RBE=∞	-50			V	
Emitter-to-Base Breakdown Voltage	V(BR)EBO	I _E = -10μA, I _C =0A	-6			V	
Turn-On Time	ton			50		ns	
Storage Time	tstg	See specified Test Circuit		450		ns	
Fall Time	tf			20		ns	

*: The 2SB1204 are classified by 0.5A hFE as follows:

Rank	Q R		S	Т	
hFE	70 to 140	100 to 200	140 to 280	200 to 400	

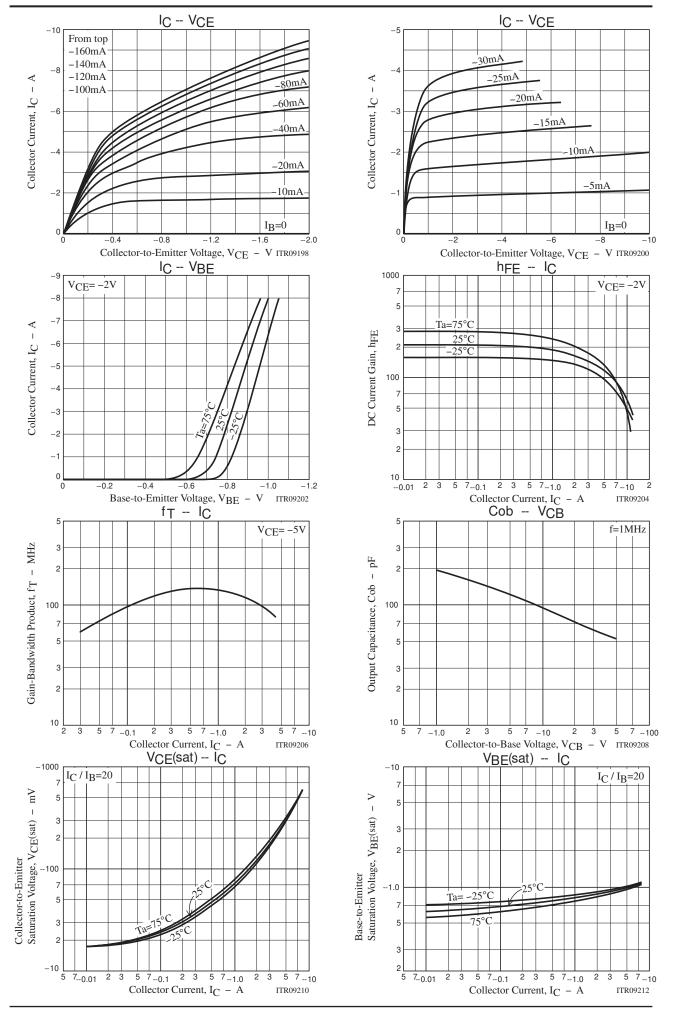
Switching Time Test Circuit

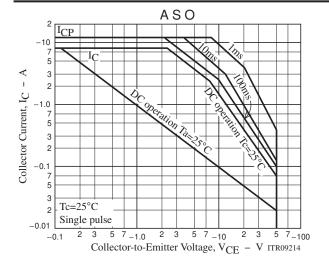


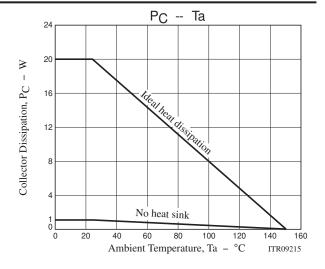
 $I_{C} = -10I_{B1} = 10I_{B2} = -4A$

Ordering Information

Device	Package	Shipping	memo
2SB1204S-E	TP	500pcs./bag	
2SB1204T-E	TP	500pcs./bag	Pb Free
2SB1204S-TL-E	TP-FA	700pcs./reel	Pb Free
2SB1204T-TL-E	TP-FA	700pcs./reel	





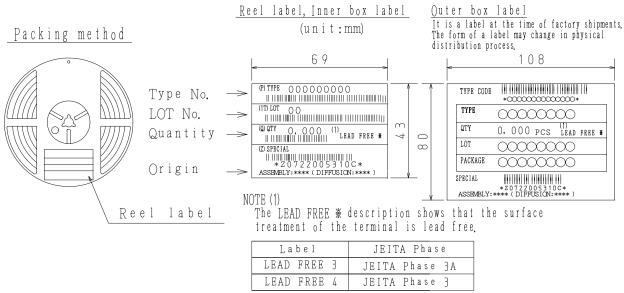


Taping Specification

2SB1204S-TL-E, 2SB1204T-TL-E

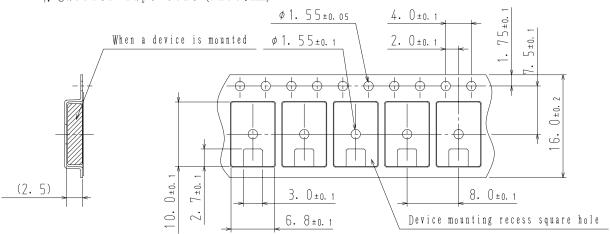
Packing Format

Package Name	Carrier Tape	Maximum Number of devices contained (pcs)			Packing	f o r m a t
	Туре	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
TP-FA	TP	700	2, 100	12, 600	3 reels contained	6 inner boxes contained
					Dimensions:mm (external)	Dimensions:mm (external)
					183×72×185	440×195×210

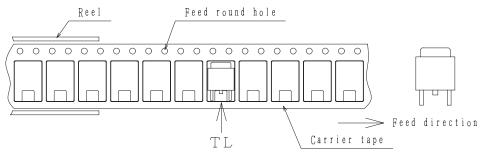


Taping configuration

1. Carrier tape size (unit:mm)



7. Device placement direction



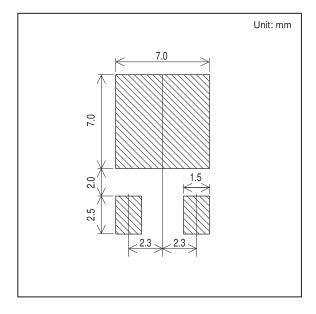
Those with one electrode terminal on the feed hole side · · · · · · TL

Outline Drawing

2SB1204S-TL-E, 2SB1204T-TL-E

Mass (g) Unit 0.282 * For reference mm 6. 5±0. 2 2. 3±0. 2 5. O±0. 2 1. 5±0. 2 0. 5±0. 1 [*1] 7.0±0.3 5. 5±0. 2 LOT No. 1. 2±0. 3 0. 5±0. 15 L 0. 85±0. 2 2. 5±0. 3 3 1. 2±0. 3 0. 6±0. 2 0~0.2 2. 3±0. 2 2. 3±0. 2 Pin 2 is idle pin with electrical designation only carried. *1:Lot indication

Land Pattern Example



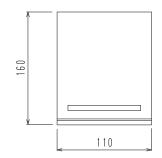
Bag Packing Specification

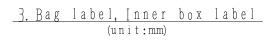
2SB1204S-E, 2SB1204T-E

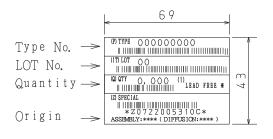
1. Packing Format

Package Name		Maximum Number of devices contained (pcs)				
1 4 0 14 6 0 14 8 110	Bag	Inner box	Outer box			
TP		B-1	A-1	A-2		
1 1	500	10,000	50,000	30,000		
		Packing format (Dimensions:mm (external))				
		Inner box Outer box		bох		
		B-1	A-1	A-2		
		445×225×55	470×250×300	470×250×190		

2. Bag dimensions (unit:mm)







4. Outer box label (unit:mm)

It is a label at the time of factory shipments, The form of a label may change in physical distribution process,

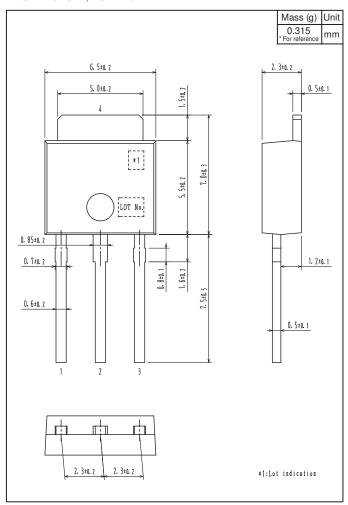


Label			JEITA Phase
LEAD	FREE	3	JEITA Phase 3A
LEAD	FREE	4	JEITA Phase 3

	TYPE CODE ************************************
	TYPE OOOOOO
	QTY O, 000 PCS LEAD FREE #
∞	LOT COCCOCCOCC
	PACKAGE COCCO
V	SPECIAL ####################################
	108

Outline Drawing

2SB1204S-E, 2SB1204T-E



- Any and all SANYO Semiconductor Co.,Ltd. products described or contained herein are, with regard to "standard application", intended for the use as general electronics equipment. The products mentioned herein shall not be intended for use for any "special application" (medical equipment whose purpose is to sustain life, aerospace instrument, nuclear control device, burning appliances, transportation machine, traffic signal system, safety equipment etc.) that shall require extremely high level of reliability and can directly threaten human lives in case of failure or malfunction of the product or may cause harm to human bodies, nor shall they grant any guarantee thereof. If you should intend to use our products for new introduction or other application different from current conditions on the usage of automotive device, communication device, office equipment, industrial equipment etc., please consult with us about usage condition (temperature, operation time etc.) prior to the intended use. If there is no consultation or inquiry before the intended use, our customer shall be solely responsible for the use.
- Specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Semiconductor Co.,Ltd. assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor Co.,Ltd. products described or contained herein.
- Regarding monolithic semiconductors, if you should intend to use this IC continuously under high temperature, high current, high voltage, or drastic temperature change, even if it is used within the range of absolute maximum ratings or operating conditions, there is a possibility of decrease reliability. Please contact us for a confirmation
- SANYO Semiconductor Co.,Ltd. strives to supply high-quality high-reliability products, however, any and all semiconductor products fail or malfunction with some probability. It is possible that these probabilistic failures or malfunction could give rise to accidents or events that could endanger human lives, trouble that could give rise to smoke or fire, or accidents that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor Co.,Ltd. products described or contained herein are controlled under any of applicable local export control laws and regulations, such products may require the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written consent of SANYO Semiconductor Co..Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor Co.,Ltd. product that you intend to use.
- Upon using the technical information or products described herein, neither warranty nor license shall be granted with regard to intellectual property rights or any other rights of SANYO Semiconductor Co.,Ltd. or any third party. SANYO Semiconductor Co.,Ltd. shall not be liable for any claim or suits with regard to a third party's intellectual property rights which has resulted from the use of the technical information and products mentioned above.

This catalog provides information as of June, 2012. Specifications and information herein are subject to change without notice.

This datasheet has been downloaded from:

www. Data sheet Catalog.com

Datasheets for electronic components.